## NSN 5961-00-116-6581

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-116-6581 **Inclosure Material:** Glass **Overall Length:** 0.265 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.096 inches **Function For Which Designed:** Varactor diode Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 50.00 milliamperes average forward current averaged over a full 60-hz cycle **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release5259 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: